

NPN Silicon Transistor

Description

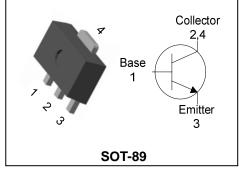
• Medium power amplifier application

Features

- P_c(Collector power dissipation)=1W (Ceramic substate of 250 m²×0.8t used)
- Low collector saturation voltage : V_{CE(sat)}=0.15V(Typ.)
- Complementary pair with STB1132

Ordering Information

PIN Connection



 $(T_{a}=25^{\circ}C)$

Type NO.	Marking	Package Code			
STD1664	A2 □YWW	SOT-89			
A2	A2: DEVICE CODE, \Box : h_{FE} rank, YWW(Y : Year code, WW : Weekly code)				

Absolute maximum ratings

Absolute maximum ratings (Ta=2				
Characteristic	Symbol	Ratings	Unit	
Collector-Base voltage	V _{CBO}	40	V	
Collector-Emitter voltage	V _{CEO}	32	V	
Emitter-Base voltage	V _{EBO}	5	V	
Collector current	Ι _C	1	A(DC)	
	I _{CP} *	2	A(Pulse)	
Collector newer discinction	Pc	0.5	W	
Collector power dissipation	P _c *	1	vv	
Junction temperature	TJ	150	°C	
Storage temperature	T _{stg}	-55~150	°C	

*: Single pulse, tp= $300 \ \mu s$

** : When mounted on ceramic substrate(250 $\mbox{mm}^2{\times}0.8t$)

Electrical Characteristics						(Ta=25°C)	
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit	
Collector-Base breakdown voltage	ВV _{сво}	$I_{c}=50 \ \mu A$, $I_{E}=0$	40	-	-	V	
Collector-Emitter breakdown voltage	BV _{CEO}	$I_c=1 \text{ MA}, I_B=0$	32	-	-	V	
Emitter-Base breakdown voltage	BV _{EBO}	Ι _E =50 μ ^A , Ι _C =0	5	-	-	V	
Collector cut-off current	I _{CBO}	V_{CB} =20V, I_E =0	-	-	0.5	μA	
Emitter cut-off current	I _{EBO}	$V_{EB}=4V$, $I_{C}=0$	-	-	0.5	μA	
DC current gain	h_{FE}^{*}	$V_{CE} = 3V$, $I_{C} = 0.1A$	100	-	320	-	
Collector-Emitter saturation voltage	V _{CE(sat)}	I_{C} =500 mA, I_{B} =50 mA	-	0.15	0.4	V	
Transition frequency	f _T	V_{CE} =5V, I_{C} =50 mA	-	150	-	MHz	
Collector output capacitance	C _{ob}	V_{CB} =10V, I_E =0, f=1 MHz	-	15	-	pF	

* : h_{FE} rank / O : 100 ~ 200, Y : 160 ~ 320

Electrical Characteristic Curves

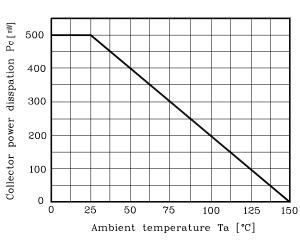
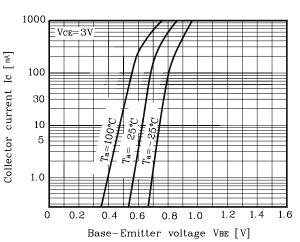


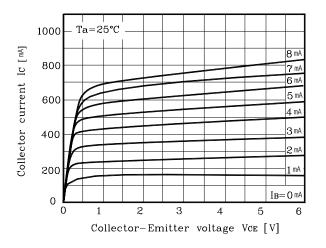
Fig. $1 P_C - T_a$











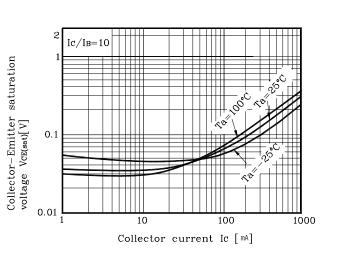
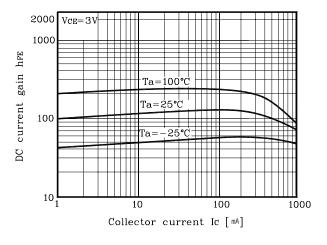
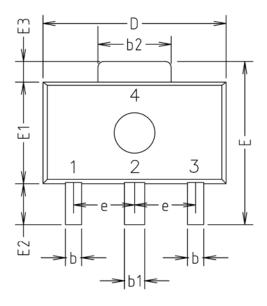
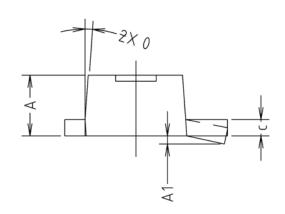


Fig. 5 h_{FE} - I_C



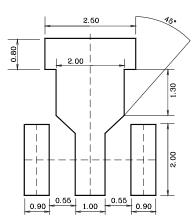
Outline Dimension(mm)





	MILLIMETERS			NOTE
SYMBOL	MINIMUM	NOMINAL	MAXIMUM	NOTE
Α	1.40	1.50	1.60	
A1	0.00	-	0.10	
b	0.38	0.42	0.48	
b1	0.48	0.52	0.58	
b2	1.79	1.82	1.87	
С	0.40	0.42	0.46	
D	4.40	4.50	4.70	
E	3.70	4.00	4.30	
E1	2.40	2.50	2.70	
E2	0.80	1.00	1.20	
E3	0.40	0.50	0.60	
е		1.50 TYP.		
θ		4° TYP.		

*Recommend PCB solder land [Unit: mm]



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